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<tr>
<td>Citation</td>
<td>Applied Physics Letters, 2007, v. 91 n. 6, article no. 063508</td>
</tr>
<tr>
<td>Issued Date</td>
<td>2007</td>
</tr>
<tr>
<td>URL</td>
<td><a href="http://hdl.handle.net/10722/57308">http://hdl.handle.net/10722/57308</a></td>
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High-efficiency orange and yellow organic light-emitting devices using platinum(II) complexes containing extended \( \pi \)-conjugated cyclometalated ligands as dopant materials

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(Received 1 May 2007; accepted 13 July 2007; published online 8 August 2007)

Two luminescent platinum(II) complexes 1 and 2 containing extended \( \pi \)-conjugated cyclometalated ligands have been used as dopant materials for the construction of two high-efficiency organic light-emitting devices I and II. Device I (containing dopant 1) emits orange emission and exhibits a maximum external quantum efficiency of 12.4\%, a maximum luminous efficiency of 32.3 cd/A, and a maximum power efficiency of 11.2 lm/W. Device II (containing dopant 2) emits yellow light and exhibits a maximum external quantum efficiency of 16.1\%, a maximum luminous efficiency of 51.8 cd/A, and a maximum power efficiency of 23.2 lm/W. © 2007 American Institute of Physics.

DOI: 10.1063/1.2768868

Bright and vibrant yellow or orange emitting materials are indispensable for the manufacture of modern multicolor visual display units. Yellow or orange colors are also important for white color displays and backlight applications, as white organic light-emitting devices (OLEDs) can often be fabricated by mixing two colors, e.g., yellow and blue, in an appropriate ratio. 1,2 Orange emissions can be obtained from fluorescent laser dye \([2\text{-}methyl-6\text{-}[2\text{-}3,6,7\text{-}trihydro\text{-}1\text{-}H, 5\text{H}-\text{benzo[j]}\text{quinolizin}\text{-}9\text{-}yl]ethenyl]\text{-}4\text{H}\text{-}pyran\text{-}4\text{-}yldene] \text{propane-dinitrile},\) but the efficiency of the as-fabricated devices is low. Indeed, high-efficiency yellow or orange OLEDs can be fabricated by using phosphor-sensitized fluorescence, 3 but this method involves uniformly codoping two dyes into a host material, which is a difficult process to control. In this regard, there has been considerable interest in the development of yellow or orange OLEDs that are efficient and have a suitable chromaticity. Electrophosphorescent OLEDs provide the most promising route to reach the high efficiency required as they are able to harness both singlet and triplet excitons generated by electrical injection. 4 Thus far, red, green, and blue electrophosphorescence devices have been demonstrated by using octahedral iridium(III) complexes, 5–10 square planar platinum(II) complexes, 11–15 and other heavy-metal complexes, such as europium(III) chelates 16, 17 and osmium(II) diimine 18 complexes, as emitting materials. However, there have been only a few published papers 19–21 on electrophosphorescent yellow or orange OLEDs.

Recently, we synthesized yellow-green to orange electrophosphorescent Pt(II) complexes \((\text{R}^\text{II}\text{C}^\text{II}\text{N}^\text{II}\text{N}^\text{II}\text{PtCl})\) containing extended \( \pi \)-conjugated cyclometalated ligands, 22 which show strong emissions with quantum yields of up to 0.68 in \( \text{CH}_2\text{Cl}_2 \) or MeCN solution. In this work, we report the construction of two high-efficiency OLEDs employing \((\text{R}^\text{II}\text{C}^\text{II}\text{N}^\text{II}\text{N}^\text{II}\text{PtCl})\) complexes as guests, which were doped into a \( 4,4\text{-}\text{N},N\text{-dicarbazole-biphenyl} \) (CBP) host. For device I (containing dopant 1), a maximum external quantum efficiency of \( \eta_{\text{ext}} =12.4\% \), a maximum luminous efficiency of \( \eta =32.3 \text{ cd/A} \), and a maximum power efficiency of \( \eta_p =11.2 \text{ lm/W} \) were achieved at a current density of \( J =3.1 \text{ mA/cm}^2 \) (10 V), corresponding to a brightness of 1100 cd/m\(^2\). The device exhibited a maximum brightness of 21 700 cd/m\(^2\) (at 17.5 V) and its Commission Internationale de L’Eclairage (CIE 1931) coordinates remained constant with increasing drive voltage. For device II (containing dopant 2), a maximum external quantum efficiency of \( \eta_{\text{ext}} =16.1\% \), a maximum luminous efficiency of \( \eta =51.8 \text{ cd/A} \), and a maximum power efficiency of \( \eta_p =23.2 \text{ lm/W} \) were achieved at a current density of \( J =0.44 \text{ mA/cm}^2 \) (7 V), corresponding to a brightness of 230 cd/m\(^2\). The device exhibited a maximum brightness of 23 500 cd/m\(^2\) (at 16 V) and nearly constant CIE coordinates \((x=0.44, y=0.54)\).

To maximize the performance of electrophosphorescent devices, it is necessary to choose a suitable host material and a hole-and-exciton-blocking layer (HBL). We chose CBP as the host because the photoluminescence spectrum of CBP overlaps with the absorption spectra of the two Pt(II) complexes used as dopants in this work. Although such spectral overlap is relevant only to the transfer of singlet states, it may, nevertheless, provide a general indication of the probability for triplet transfer. 6 Furthermore, we chose 2,9-dimethyl-4,7-diphenyl-1,10-phenanthroline (bathocuprine, BCP) for the HBL because of its deep highest occupied molecular orbital (HOMO) energy (6.5 eV), 15 which can confine both holes and excitons within the emitting layer. The hole transporting layer (HTL) was \( N,N\text{-diphenyl-N,N\text{-bis}(1\text{-naphthyl)phenyl)-1,1\text{-biphenyl-4,4\text{-diamine (NPB)}}} \) and the electron transporting layer (ETL) was BCP. The combined use of ETL and HBL eliminates the requirement for additional electron transporting material and simplifies the overall device architecture. Device architecture and...
chemical structure of the two Pt(II) complexes are depicted in Fig. 1. Devices I and II share the same architecture but contain different dopants.

The organic layers were deposited by thermal evaporation onto a cleaned glass substrate precoated with transparent, conductive indium tin oxide under a vacuum of 10⁻⁵ Torr. A 30-nm-thick film of NPB was first deposited as the HTL. A 20-nm-thick CBP host was then deposited, which was doped with 1–10 wt % of dopant 1 or 2. The doping level was controlled by varying the relative deposition rates of CBP and Pt(II) complexes. Next, a 40-nm-thick layer of BCP was deposited as the ETL and HBL. A shadow mask with a 3×3 mm² opening was used to define the cathode, which consisted of a 0.5-nm-thick layer of LiF with a 100-mm-thick aluminum cap. The electroluminescent (EL) spectra, brightness, and CIE coordinates (CIE 1931) of the OLEDs were measured with a Photo Research Inc. PR650 luminance meter. The luminance-current density–voltage characteristics were recorded simultaneously, with the EL spectra measured by combining a luminance meter with a Keithley model 2400 voltage-current source. All measurements were carried out at room temperature under ambient conditions.

To determine the optimal dopant concentration, OLEDs with different dopant concentrations were fabricated to examine the relationship between the luminous efficiency and the concentration of dopant used. For dopant 1, the optimal dopant concentration was around 5 wt %, at which value device I exhibited a maximal luminous efficiency of 32.3 cd/A. For dopant 2, the optimal doping level was 6 wt %, where device II showed a maximal luminous efficiency of 51.8 cd/A. Figure 2 shows the EL spectra for devices I and II at different applied voltages. Device I emitted bright orange light, and the EL spectrum showed a peak maximum at 553 nm with a shoulder at λ = 594 nm. Its EL spectra and CIE coordinates are independent of current. When the applied voltage was increased from 4 to 18 V (corresponding to a current density of 0.076–388.9 mA/cm²), the CIE coordinates only changed from (0.461, 0.508) to (0.474, 0.507), indicating excellent color stability. Device II emitted yellow light, and the EL spectrum had a major intensity peak at λ_max = 540 nm, with another intensity peak at λ = 580 nm. Its EL spectra and CIE coordinates are also independent of current, only changing from (0.423, 0.546) to (0.440, 0.537) when the applied voltage was increased from 4 to 16 V.

Figure 3 shows the external quantum efficiency (η_ext) and power efficiency (η_p) as a function of current density for devices I and II with optimized dopant concentration. For device I (with 5 wt % of dopant 1, as shown in Fig. 3(a)), the maximum η_ext = 12.4 % and η_p = 11.2 lm/W were achieved at a current density of J = 3.1 mA/cm² (10 V). The η_ext increased with increasing current at small current density (J < 1 mA/cm²). Device I exhibited a gradual decrease of η_ext with increasing current, which could be attributed to triplet-triplet annihilation.23 Even at a higher current density of J = 111 mA/cm² (15 V), the efficiency of device I remained high at η_ext = 4.5 % and η_p = 2.4 lm/W. For device II (with 6 wt % of complex 2, as shown in Fig. 3(b)), the maximum η_ext = 16.1 % and η_p = 23.2 lm/W were achieved at a current density of J = 0.44 mA/cm² (7 V), corresponding to a brightness of 230 cd/m². At the higher current density of J = 188.9 mA/cm² (15 V), the device efficiency remained high at η_ext = 3.6 %, η_L = 11.2 cd/A, and η_p = 2.3 lm/W. The luminous, quantum and power efficiencies of our OLEDs are superior to those of phosphor-sensitized fluorescent OLEDs,4.
and two or three times higher than that reported recently for
Pt(II) complexes19 and for iridium complexes.20,21 The
reason why the external quantum efficiency of device I is sig-
ificantly lower than that of device II may be due to the dif-
ference in emission quantum yield of the dopants. The
emission quantum yield of dopant 1 in CH2Cl2 solution is
0.02,22 which is significantly lower than that of 0.68 of dop-
ant 2 in the same solution.

Figure 4 shows the brightness–current density–applied voltage
curves of devices I and II. For device I, the turn-on voltage
of the device was ~5 V for a luminescence of 1 cd/m2 and a
maximum brightness of 21 700 cd/m2 was achieved at a current
density of J=326 mA/cm2 (17.5 V). The benchmark luminescence of 100 cd/m2 was reached at a voltage of 7.4 V, cor-
responding to a current density of 0.19 mA/cm2. For device II, its turn-on voltage was ~4.2 V for 1 cd/m2 and a
maximum brightness of 23 500 cd/m2 was reached at a current density of J=222.2 mA/cm2 (15.5 V). The benchmark luminescence of 100 cd/m2 was reached at a voltage of 6.4 V, corre-
sponding to a current density of 0.31 mA/cm2. An interesting feature could be noted from Fig. 4, where device II shows higher current den-
sities than device I at lower voltages. This is a reproducible
finding even at the same dopant concentration. This implies
that both charge injection and transport behavior for dopants
1 and 2 are different. The difference is tied to respective
different HOMO and lowest unoccupied molecular orbital
(LUMO) levels. In this work, the HOMO and LUMO energy
levels of dopants 1 and 2 were estimated from their electro-
chemical data, which were measured by cyclic voltammetry
(CV) using Ag/Ag+ electrode in 10−4 M DMF solution. The
HOMO and LUMO levels of dopant 1 are 5.63 and 3.14 eV, and obtained 5.38 and 3.07 eV for dopant 2. The HOMO and
LUMO levels of CBP are from Ref. 23, where they were
determined by CV method to be 6.0 and 2.7 eV, respectively.
Because the HOMO level of dopant 2 is 0.25 eV higher than
that of dopant 1, the barrier to hole injection into dopant 2
from NPB is 0.25 eV lower than that to hole injection into
dopant 1 from NPB; i.e., hole injection into dopant 2 from
NPB is energetically more favorable than into dopant 1 at
the same applied voltages. On the other hand, the LUMO level
of dopant 1 is 0.07 eV lower than that of dopant 2. This
means that the trap effect of dopant 1 is more effective than
dopant 2 in trapping electrons. Once electrons are trapped,
the mobility of electrons in CBP decreases, leading to the
decline of the current density at the same voltages.

In summary, we have fabricated high-efficiency orange
and yellow organic light-emitting devices using phosphores-
cent platinum(II) complexes as dopant materials. The use of
[(RC=NR)PtCl] complexes provides an entry to a family of
electrophosphorescent yellow emitters.

The authors gratefully acknowledge support from the
University Development Fund (Nanotechnology Research
Institute, 00600009), the Strategic Research Theme on “Or-

ganic Optoelectronics,” the Faculty Development Fund of the
Science Faculty of The University of Hong Kong, the
Research Grants Council of the HKSAR, China (HKU 7039/
03P), the Seed Funding Programme for Basic Research
(200411159167 and 200611159062), and the Innovation and
Technology Commission of the Hong Kong SAR Govern-
ment (ITF GHP/062/05).

FIG. 4. (Color online) Luminance–applied voltage–current density curves of
device I (solid) and device II (open). Circles stand for current density and
squares represent brightness.

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